L Number	Hits	Search Text	DB	Time stamp
1	2835863	memory or storage	USPAT;	2004/06/24 15:01
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
2	140401	(memory or storage) and (nonvolatile or non-volatile or	USPAT;	2004/06/24 15:03
		floating adj gate)	US-PGPUB;	
			EPO; JPO;	
	2000		DERWENT	
3	2068	((memory or storage) and (nonvolatile or non-volatile or	USPAT;	2004/06/24 15:03
	-	floating adj gate)) and capacitor and flip-flop	US-PGPUB;	
			EPO; JPO; DERWENT	
4	2	(((memory or storage) and (nonvolatile or non-volatile or	USPAT;	2004/06/24 15:05
	2	floating adj gate)) and capacitor and flip-flop) and transistor	US-PGPUB;	2004/00/24 13.03
		with charge with capacitor with gate with boost\$5	EPO; JPO;	
		War charge war capacitor war gate war 5003tp3	DERWENT	
5	4	(((memory or storage) and (nonvolatile or non-volatile or	USPAT;	2004/06/24 15:05
-	•	floating adj gate)) and capacitor and flip-flop) and charge	US-PGPUB;	==== 1, ==, == 1
		with capacitor with gate with boost\$5	EPO; JPO;	
			DERWENT	